



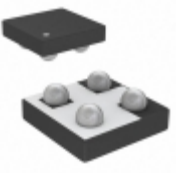

	<h2>SI8404DB-T1-E1</h2>
	<p>Hersteller-Teilenummer: SI8404DB-T1-E1</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 8V 12.2A 2X2 4-MFP</p> <p>Datenblätter:  SI8404DB-T1-E1.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 18000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI8404DB-T1-E1
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 8V 12.2A 2X2 4-MFP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	18000 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	4-XFBGA, CSPBGA
Supplier Device-Gehäuse	4-Microfoot
Verlustleistung (max)	2.78W (Ta), 6.25W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	8V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12.2A (Tc)
Rds On (Max) @ Id, Vgs	31 mOhm @ 1A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	33nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1950pF @ 4V
Verpackung	Tape & Reel (TR)



















































SI8404DB-T1-E1 ist neu im Original, Suche SI8404DB-T1-E1 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI8404DB-T1-E1 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI8404DB-T1-E1: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI8405AA-A-IS1R Energy Micro (Silicon Labs) DGTL ISOLATOR 1KV 4CH I2C 16SOIC</p>	 <p>SI8405AA-A-IS1 Energy Micro (Silicon Labs) DGTL ISOLATOR 1KV 4CH I2C 16SOIC</p>	 <p>SI8402DB-T1-E1 Vishay / Siliconix MOSFET N-CH 20V 5.3A 2X2 4-MFP</p>	 <p>SI8402DB-T1-E1. VIS SI8402DB-T1-E1. VIS</p>
 <p>SI8402DB-T1 VISHAY SI8402DB-T1 VISHAY</p>	 <p>SI8404DB-T1-E1 Electro-Films (EFI) / Vishay MOSFET N-CH 8V 12.2A 2X2 4-MFP</p>	 <p>SI8402DB-T1-E1 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 5.3A 2X2 4-MFP</p>	 <p>SI8405AA-B-IS1 Energy Micro (Silicon Labs) DGTL ISOLATOR 1KV 4CH I2C 16SOIC</p>

heiße Teile

Mehr

 SI8252-IMR	 SI8261AAC-C-IS	 SI8261ABD-C-IS	 SI8261ACC-C-IS	 SI8261BAC-C-IPR
 SI8261BAC-C-IS	 SI8261BAD-C-IS	 SI8261BBC-C-IS	 SI8261BBD-C-IS	 SI8261BCC-C-IP
 SI8261BCC-C-IS	 SI8261BCD-C-IS	 SI8388P-IU	 SI8400AA-B-IS	 SI8400AB-B-ISR
 SI8401DB-T1	 SI8401DB-T1-E1	 SI8401DB-T1-E1	 SI8401DB-T1-E3	 SI8401DB-T1-E3
 SI8402DB-T1	 SI8402DB-T1-E1	 SI8402DB-T1-E1	 SI8402DB-T1-E1.	 SI8402DB-T1-E3
 SI8404DB-T1-E1	 SI8405DB	 SI8405DB-T1	 SI8405DB-T1-E1	 SI8405DB-T1-E1
 SI8405DB-T1-E3	 SI8405DB-T1-E3	 SI8409DB-T1	 SI8409DB-T1-E1	 SI8409DB-T1-E1
 SI8410AB	 SI8410BB-D-ISR	 SI8410BB-I-DS	 SI8413DB-T1-E1	 SI8413DB-T1-E1
 SI8415DB-T1	 SI8415DB-T1-E1	 SI8415DB-T1-E1	 SI8417DB-T2-E1	 SI8417DB-T2-E1
 SI8420BB	 SI8420BB-D-IS	 SI8421AB-D-ISR	 SI8422AB-D-ISR	 SI8422BD

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